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器件驱动与控制

有机电致发光器件薄膜封装研究进展

高淑雅[1], 孔祥朝[1], 张方辉[2], 吕磊[1]

1. 陕西科技大学 材料科学与工程学院, 陕西 西安 710021;
2. 陕西科技大学 电气与信息工程学院, 陕西 西安 710021

摘要： 有机电致发光器件(OLEDs)对水汽和氧气非常敏感,渗入OLEDs内的水汽和氧气会腐蚀有机功能层及电极材料,严重影响器件寿命。文中根据OLEDs对封装材料的要求,分析了目前最有前景的OLEDs封装技术——薄膜封装,重点介绍了薄膜封装的分类和研究现状。

关键词： 有机电致发光器件 薄膜封装 老化机制

Research Progress of Thin Film Encapsulation of Organic Light-Emitting Devices

GAO Shu-ya[1], KONG Xiang-zhao[1], ZHANG Fang-hui[2], LV Lei[1]

1. School of Material Science & Engineering, Shaanxi University of Science & Technology, Xi'an 710021, China;
2. School of Electrical & Information Engineering, Shaanxi University of Science & Technology, Xi'an 710021, China

Abstract: Organic light-emitting devices (OLEDs) are extremely sensitive to vapor and oxygen. The influence of inleakage of vapor and oxygen which can corrode organic functional layer and the electrode material on device's lifetime was serious. Based on the requirements of encapsulation materials, this paper analyzes the most promising OLEDs encapsulation technology —thin film encapsulation, which mainly focuses on the classification and research status.

Keywords: OLEDs thin film encapsulation aging mechanisms

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通讯作者:

作者简介:

作者Email:

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